

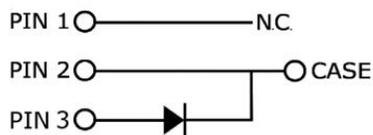
S3D35065D1 650V SiC POWER SCHOTTKY RECTIFIER



Description

S3D35065D1 is a SiC Schottky rectifier packaged in TO-247AD(TO-247-3) case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D35065D1 is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 650 | V |
| Average Rectified Forward Current | I _{F(AV)} | 50% duty cycle @T _c =150°C, rectangular wave form | 35 | A |
| Peak One Cycle Non-Repetitive Surge Current | I _{FSM} | 10ms, Half Sine pulse, T _J =25°C | 400 | A |
| Repetitive Peak Forward Surge Current | I _{FRM} | 10 ms, Half Sine pulse, T _J =25°C | 210 | A |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Typ. | Max. | Units |
|----------------------------------|-----------------|---|------|------|-------|
| Forward Voltage Drop* | V _{F1} | @ 35A, Pulse, T _J = 25 °C | 1.5 | 1.7 | V |
| | V _{F2} | @ 35A, Pulse, T _J = 175 °C | 2.0 | 2.4 | V |
| Reverse Current at DC condition* | I _{R1} | @V _R = rated V _R T _J = 25 °C | 0.08 | 45 | uA |
| Reverse Current * | I _{R2} | @V _R = rated V _R T _J = 175 °C | 1 | 70 | uA |
| Junction Capacitance | C _T | V _R =0V, T _J =25°C, f=1MHz | 2000 | - | pF |

* Pulse width < 300 μs, duty cycle < 2%

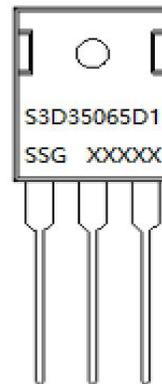
Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|------------------|--------------|---------------------------------|-------|
| Junction Temperature | T _J | - | -55 to +175 | °C |
| Storage Temperature | T _{stg} | - | -55 to +175 | °C |
| Typical Thermal Resistance Junction to Case | R _{θJC} | DC operation | 0.84(per leg) 0.42(both leg) | °C/W |

Ordering Information

| Device | Package | Shipping |
|------------|------------------------|-------------|
| S3D35065D1 | TO-247AD (TO-247-3) | 25pcs /tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram


Where XXXXX is YYWWL

S3D = Device Type
D1 = Package type
35 = Forward Current (35A)
065 = Reverse Voltage (650V)
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ratings and Characteristics Curves

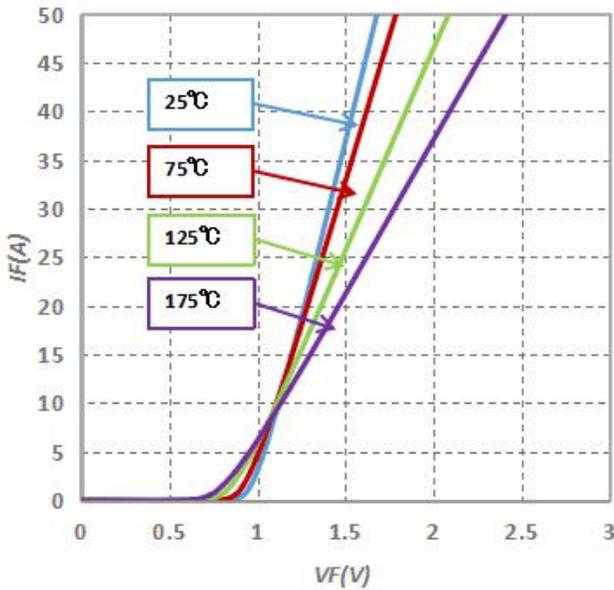


Fig.1-Typical Forward Voltage Characteristics

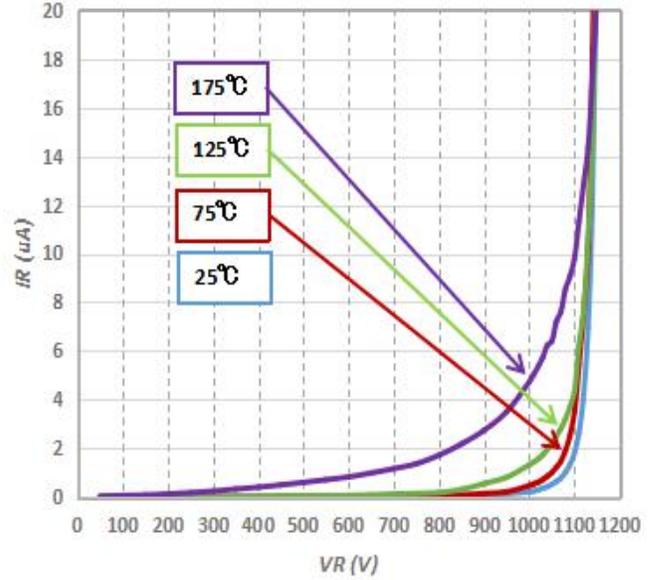


Fig.2-Typical Reverse Characteristics

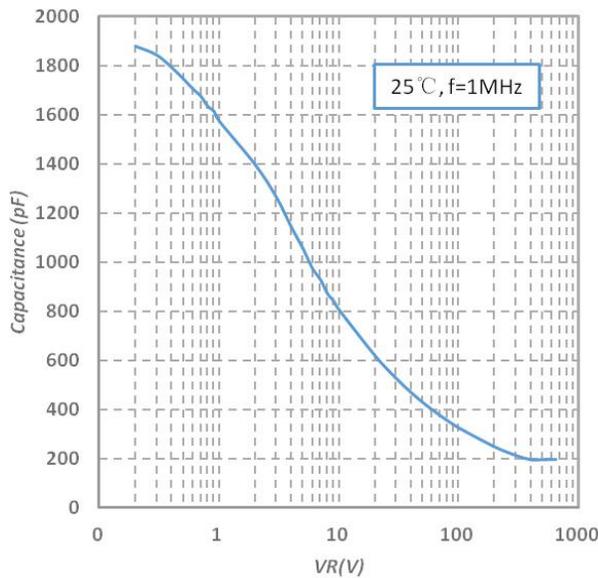
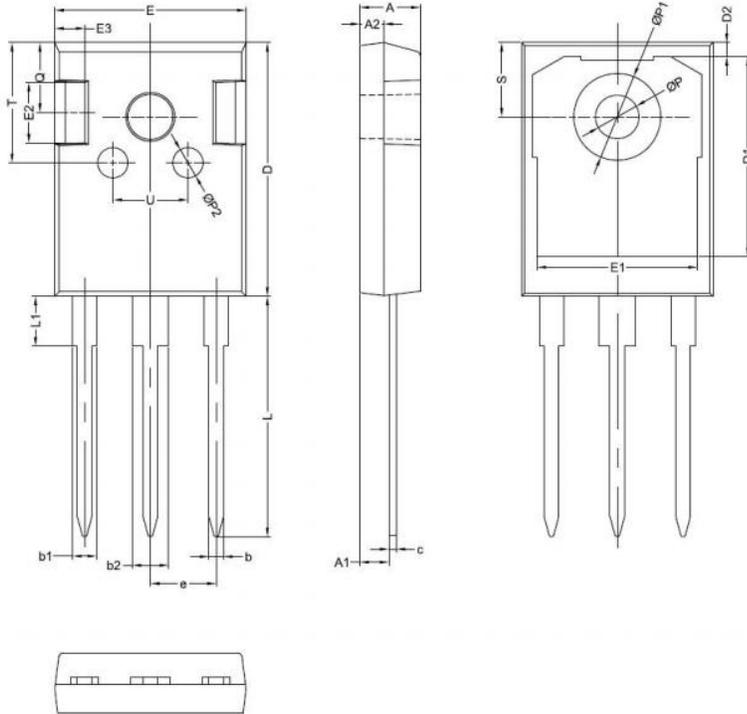


Fig.3-Capacitance vs. Reverse Voltage

Mechanical Dimensions TO-247AD



| SYMBOL | Millimeters | | |
|--------|-------------|-------|-------|
| | MIN. | TYP. | MAX. |
| A | 4.80 | 5.00 | 5.20 |
| A1 | 2.20 | 2.41 | 2.61 |
| A2 | 1.90 | 2.00 | 2.10 |
| b | 1.10 | 1.20 | 1.40 |
| b1 | 1.80 | 2.00 | 2.20 |
| b2 | 2.80 | 3.00 | 3.20 |
| c | 0.50 | 0.60 | 0.75 |
| D | 20.30 | 21.00 | 21.20 |
| D1 | | 16.55 | |
| D2 | | 1.20 | |
| E | 15.45 | 15.80 | 16.00 |
| E1 | | 13.30 | |
| E2 | | 5.00 | |
| E3 | | 2.50 | |
| e | | 5.44 | |
| L | 19.42 | 19.92 | 20.70 |
| L1 | | 4.13 | |
| P | 3.50 | 3.60 | 3.70 |
| P1 | 7.1 | | 7.40 |
| P2 | | 2.50 | |
| Q | | 5.80 | |
| S | 6.05 | 6.15 | 6.25 |
| T | | 10.00 | |
| U | | 6.20 | |



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